



DMP4006SPSW

40V P-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) max	I _D Tc = +25°С	
-40V	5.2mΩ @ V _{GS} = -10V	-115A	
-40 V	7.9mΩ @ V _{GS} = -6V	-94A	

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Reverse Polarity Protection
- BLDC Motor Control
- Power Management Functions
- System/Load Switch

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

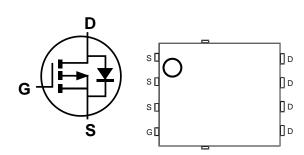


PowerDI5060-8 (SWP) (Type UX)

Top View



Bottom View



Internal Schematic

Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP4006SPSW-13	PowerDI5060-8 (SWP) (Type UX)	2,500 / Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

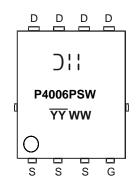
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

PowerDI is a registered trademark of Diodes Incorporated. DMP4006SPSW Document number: DS43086 Rev. 2 - 2



Marking Information



 \bigcirc | | = Manufacturer's Marking P4006PSW = Product Type Marking Code $\overrightarrow{YY}WW$ = Date Code Marking \overrightarrow{YY} = Year (ex: 21 = 2021) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-40	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = -10V	Steady State	Tc = +25°C Tc = +70°C	ID	-115 -92	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	-460	A
Maximum Body Diode Continuous Current			Is	-115	A
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			lsм	-460	A
Avalanche Current (L =0.1mH)			las	-72	A
Avalanche Energy (L = 0.1mH)			E _{AS}	262	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	36.5	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	104	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.2	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



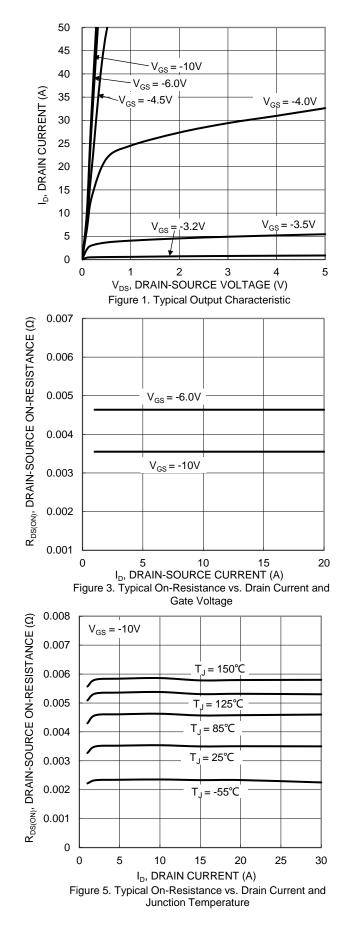
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

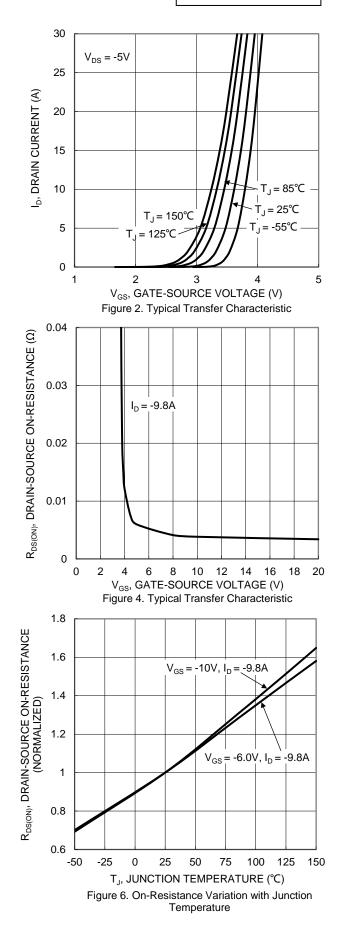
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)					•		
Drain-Source Breakdown Voltage	BVDSS	-40	—	—	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_		-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS			±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-2.0	_	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Descer	_	3.6	5.2	mΩ	Vgs = -10V, Ip = -9.8A	
Static Drain-Source On-Resistance	Rds(on)	—	4.5	7.9	ms2	$V_{GS} = -6V, I_D = -9.8A$	
Diode Forward Voltage	V _{SD}	_	-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	6855	_		V _{DS} = -20V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	883	_	pF		
Reverse Transfer Capacitance	Crss	_	526	_			
Gate Resistance	Rg	_	7.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg	_	162	_			
Gate-Source Charge	Qgs	_	28	_	nC	V _{DS} = -20V, I _D = -9.8A	
Gate-Drain Charge	Q _{gd}	_	38	_			
Turn-On Delay Time	tD(ON)	_	28	_		V _{GS} = -10V, V _{DD} = -20V,	
Turn-On Rise Time	tR	_	32	_	1		
Turn-Off Delay Time	tD(OFF)		469		ns	$R_G = 6\Omega$, $I_D = -9.8A$	
Turn-Off Fall Time	t⊧	_	228	_			
Reverse Recovery Time	t _{RR}	_	44	_	ns	I _F = -9.8A, di/dt = -100A/µs	
Reverse Recovery Charge	Qrr	_	48	_	nC	I _F = -9.8A, di/dt = -100A/µs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



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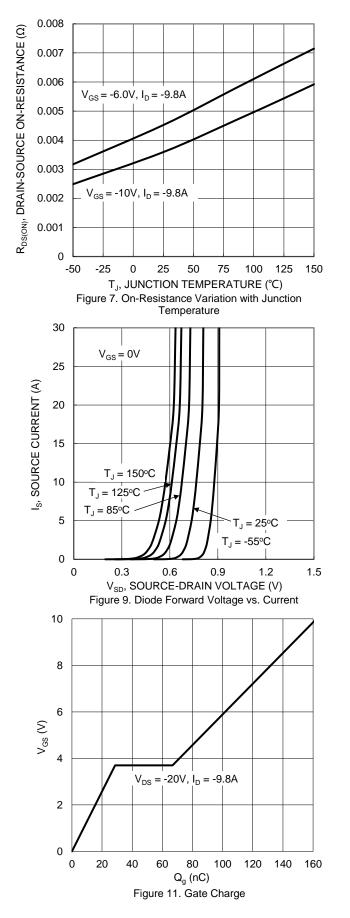


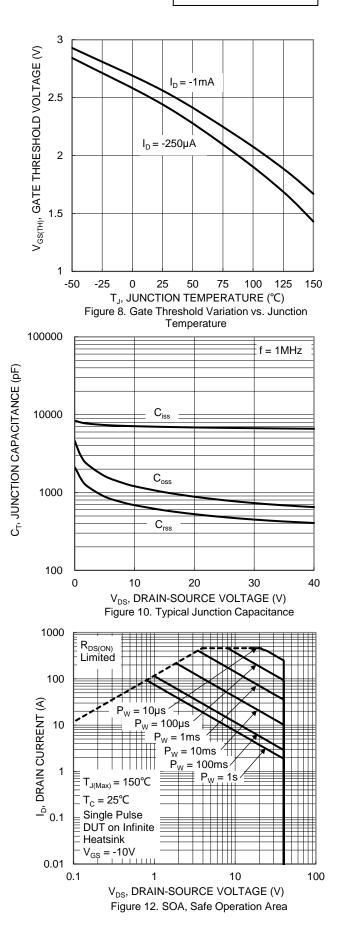


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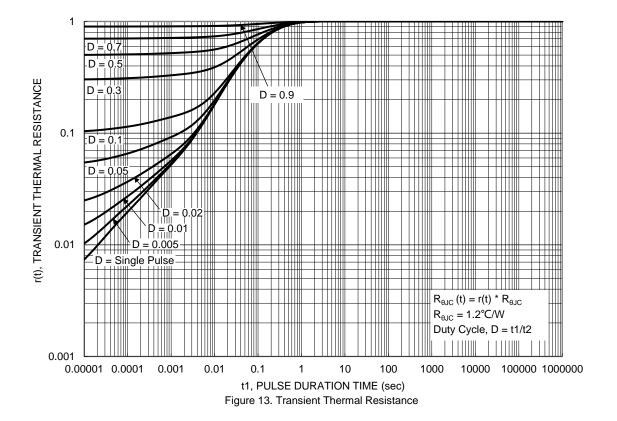




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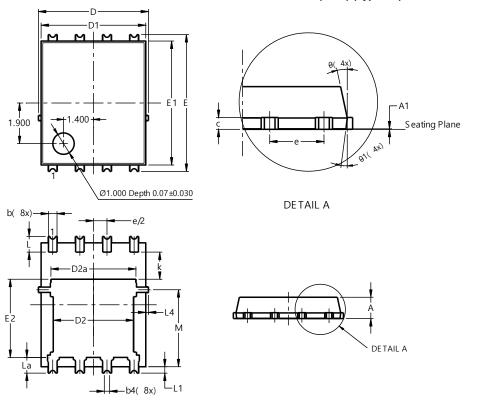




PowerDI5060-8 (SWP)

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



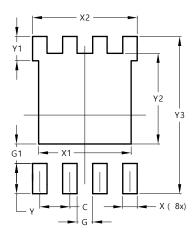
PowerDI5060-8 (SWP) (Type UX)

(Type UX) Dim Min Max Тур 0.90 1.10 1.00 Α A1 0 0.05 --b 0.30 0.50 0.41 0.20 0.25 b2 0.35 b4 0.25REF С 0.230 0.330 0.277 D 5.15 BS D1 4.70 5.10 4.90 D2 3.56 3.96 3.76 D2a 3.78 4.18 3.98 6.40 BS Ε E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 1.27BSC е k 1.05 ---L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 Μ 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7° All Dimensions in mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value			
Dimensions	(in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	4.420			
Y	1.270			
Y1	1.020			
Y2	3.810			
Y3	6.610			



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